

Part Number: CHP-107

High Power Chip Multi-Mode Fabry-Perot CW Wavelength at 1470nm



Features

- High Output Power
- High Dynamic Range
- High Efficiency
- Standard Bare Die
- Cost Effective

Application

Professional Medical



SemiNex delivers the highest available power at infrared wavelengths between 12xx and 19xx nm. When necessary, we will further optimize the design of our InP & GaSb laser chips to meet our customers' specific optical and electrical performance needs. Diodes, bars and packages are tested to meet customer and market performance demands. Typical results and packaging options are shown. Contact SemiNex for additional details or to discuss your specific requirements.



Specification

CHP-107



Optical	Symbol	Тур.	Units
Center Wavelength	λ _c	1470	nm (±20)
Output Power (CW)*	Pout	7	watts (±10%)
Chip Cavity Length	CL	2500	μm
Emitter Width	W	180	μm
Spectral Width FWHM	Δλ	15	nm
Slope Efficiency	η	0.37	W/A
Fast Axis Div.	ΘΤ	28	deg FWHM
Slow Axis Div.	Θ	9	deg FWHM
Electrical			
Electrical	Symbol		Units
Power Conversion Eff.	Symbol	21	Units %
		21 0.5	
Power Conversion Eff.	η		%
Power Conversion Eff. Threshold Current	η Ітн	0.5	% A
Power Conversion Eff. Threshold Current Operating Current	η Ітн Іор	0.5 21	% A A
Power Conversion Eff. Threshold Current Operating Current Operating Voltage	η Ітн Іор	0.5 21 1.7	% A A V

*Specified values are rated at a constant heat sink temperature of 20°C.

**High temperature operation will reduce performance and MTTF.

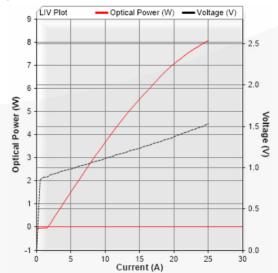
Unless otherwise indicated all values are nominal.



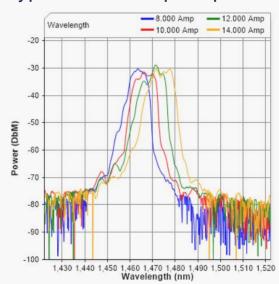
SemiNex Laser Diodes CHP-107

Graphs & Data

Typical CHP L-I-V Characteristics



Typical CHP Output Spectrum



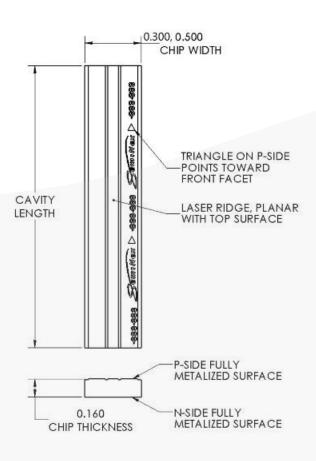
*Graphs and Data were collected from mounted parts

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Mechanical Drawing





CHIP ATTRIBUTES

APERTURE WIDTH (µm)	Single Mode (4, 5) ± 1 Multi Mode (50, 95, 180, 350) ± 3
CHIP WIDTH (µm)	300, 500 ± 10
THICKNESS (µm)	160 ± 10
CAVITY LENGTH (µm)	Varies ± 10

P METALIZATION

MATERIAL	THICKNESS (nm)	TOLERANCE (nm)
Ti	50	± 10
Pt	125	± 25
Au	250	± 50

N METALIZATION

MATERIAL	THICKNESS (nm)	TOLERANCE (nm)
Ti	30	± 10
Pt	125	± 25
Au	400	± 40

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